

Docket No.: 050432-0657



**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of : Customer Number: 20277  
MARK T. RAMSBEY, et al. : Confirmation Number: 9931  
Application No.: 10/718,707 : Group Art Unit: 2822  
Filed: November 24, 2003 : Examiner: Duong, Khanh B.

For: METHODS FOR FORMING NITROGEN-RICH REGIONS IN NON-VOLATILE SEMICONDUCTOR MEMORY DEVICES (As Amended)

**COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE**

Mail Stop Issue Fee  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Please enter the following remarks in response to the Examiner's Comments On Statement of Reasons for Allowance that accompanied the Notice of Allowance dated August 11, 2005.